

1. Description

This series are state-of-the-art devices designed for use in switching power supplies, inverters and as free wheeling diodes.

2. Features

- n Ultrafast 25 nanosecond recovery time
- n 175°C operating junction temperature
- n Epoxy meets UL 94 V-0 @ 0.125 in
- n Low forward voltage
- n Low leakage current
- n High temperature glass passivated junction
- n Reverse voltage to 700 V
- n Pb-free packages are available

3. Mechanical Characteristics

n Case: epoxy, molded

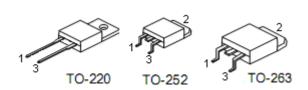
n Weight: 1.9 grams (approximately)

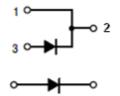
n Finish: all external surfaces corrosion resistant and terminal

n Leads are readily solderable

n Lead temperature for soldering purposes: 260°C max for 10 seconds

4. Pin configuration





Pin (TO-220)	Function		
1	Cathode		
3	Anode		

Pin (TO-252、 TO-263)	Function
1	Cathode
2	Cathode
3	Anode



5. Maximum ratings

Parameter	Symbol	Symbol Rating	
Peak repetitive reverse voltage Working peak reverse voltage DC blocking voltage	V _{RRM} V _{RWM} V _R	700	V
Average rectified forward current Total device, (Rated VR), $T_C = 150$ °C	I _{F(AV)}	8.0	А
Peak repetitive forward current (Rated VR, square wave, 20 kHz), T _C = 150°C	I _{FM}	16	А
Nonrepetitive peak surge current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	I _{FSM}	100	А
Operating junction temperature and storage temperature range	T_J, T_stg	-65 to +175	°C

6. Thermal characteristics

Parameter	Symbol	Rating	Unit
Maximum thermal resistance, junction-to-case	R _{θJC}	2.0	°C/W

7. Electrical characteristics

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Parameter	Symbol Conditions		Min	Тур	Max	Unit	
Maximum Instantaneous Forward Voltage (Note 1)	V _F	I _F =8.0A, T _C =25°C		-	1.8	2.6	V
Maximum Instantaneous Reverse Current (Note 1)	1_	V _R =600V	T _J =150°C	-	-	500	
	IR		T _J =25°C	-	-	25	μA
Maximum Reverse Recovery Time	t _{rr}	I _F =0.5A, I _R =1.0A, I _{REC} =0.25A		-	-	30	ns

Note:1. Pulse test: pulse width=5ms, Duty cycle ≤2.0%.